| Departm            | artment Elective – II   |  |                                  |      | т                     | Р          | С        |  |
|--------------------|---|--|----------------------------------|------|-----------------------|------------|----------|--|
| Ifth yea<br>A.Sc \ | ar of Five Years integr<br>/, Semester – IX   | ated M. Sc. (Physics)  | 3                                |      | 0                     | 0          | 3        |  |
| IP 553:            |   | Material Science   |                                  |      |                       |            |          |  |
| •                  | <b>INTRODUTION TO CRYSTAL GROWTH</b><br>Materials and civilization, structure properties performance, classification of materials, states of matter, theory of liquids, transition between states of matter, energetics of transitions, structure of solids, crystallization, three dimensional bonding, interatomic distances, generalization based on bonding, formation of amorphous solids, metallic glasses, colloidal state of matter, gels, emulsions, liquid crystals, plasma state of matter, advanced materials, composite materials, modern materials needs, Polymeric materials, Organic Semiconductors, Ceramics.  |  |                                  |      |                       | (06 H      | Hours)   |  |
| •                  | PHASE EQUILIBRIUM AND NUCLEATION<br>Phase diagrams, definition and basic concepts, Gibb's phase rule, one<br>component and two component phase diagrams, properties of phases in<br>materials, crystalline and non-crystalline phases, practical aspects of phase<br>diagram, non-equilibrium in phase diagrams, iron carbon alloy, Phase<br>deformation in materials, nucleation, growth of nuclei, solidification of alloys,<br>common phase transformations in solid materials.  |  |                                  |      |                       | (08 Hours) |          |  |
| •                  | <b>GROWTH TECHNIQUES</b><br>Crystal Growth from Melt, Solution, Vapour, Hydrothermal synthesis etc.,<br>Epitaxial Techniques, Liquid Phase Epitaxy, Vapour Phase Epitaxy, Metal<br>Organic Chemical Vapour Deposition (MOCVD), Molecular Beam Epitaxy<br>(CBE), Atomic Layer Epitaxy (ALE)  |  |                                  |      | ,<br> <br>/           | (08 Hours) |          |  |
| •                  | <ul> <li>MATERIAL PROPERTIES AND CHARACTERIZATION</li> <li>Points defects in solids, lattice vacancies, colour centres produced by irradiation with x-rays, methods of characterizations, single crystal technique, Fourier computational methods, techniques and applications of neutron diffraction, comparison of neutron and X-ray diffraction, Elastic and plastic behaviour of materials, viscous and viscoelastic deformation, character of plastic flow, deformation of crystalline materials, plastic deformation, creep fracture, fatigue, hardness, Magnetic properties, types of magnetic materials, applications, Optical properties of metals and non-metals, optical materials, luminescence excitation and emersion, decay mechanisms, thallium activated alkali halides, electroluminescence.</li> <li>MANOMATERIALS</li> <li>Intoroduction to nanomaterials, Fabrication of nanomaterials, Properties of materials at nano-scale, The era of new nanostructures of Carbon, Carbon Nano Tubes, Characterization of nanostructures, SPM, STM, AFM, SEM, TEM.</li> <li>MATERIALS DESIGN FOR SEMICONDUCTOR DEVICES</li> <li>Semiconductor optoelectronic properties, III-V materials selection, semiconductor device structure for laser diodes, light emitting diodes (LED's), Photo cathodes. Microwave field-effect transistor.</li> </ul> |  |                                  |      | n<br>r<br>,<br>,<br>, | (08 H      | Hours)   |  |
| •                  |   |  |                                  |      | f                     | (06 H      | lours)   |  |
| •                  |   |  |                                  |      | ,                     | (06 H      | lours)   |  |
|                    |   | (Тс  | otal Contact Hours (Th           | eory | ():                   | 42 Ho      | ours)    |  |
| OOKS               | RECOMMENDED:  | Matoriala Salance and  | Wilow                            |      |                       | 40         | 07       |  |
| 1. 0               |   | Engineering  | vviley                           |      |                       | 19         | 91       |  |
| 2. H               | lertyman P.   | Crystal Growth   | Elsevier                         |      |                       | 19         | 73       |  |
| 3. G               | iuy A.G.  | Essentials of materials<br>science                                 | McGraw Hill                      |      |                       | 19         | 76       |  |
| 4. P<br>5. V       | Pemplin B.R.<br>/anvleck L.H.   | Crystal Growth<br>Elements of Materials<br>Science and Engineering | Pergamon Press<br>Addison Wesley |      |                       | 19<br>19   | 80<br>99 |  |